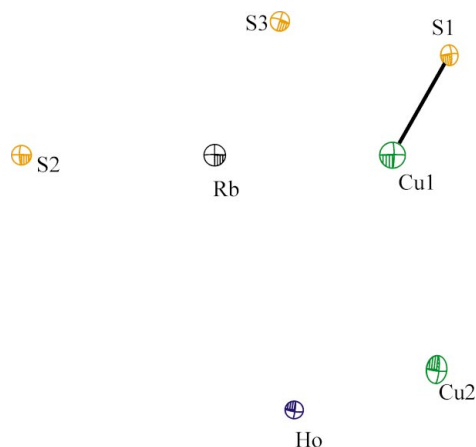


RbHo₂Cu₃S₅**Jiyong Yao and James A. Ibers***Department of Chemistry, Northwestern
University, 2145 Sheridan Road, Evanston,
IL 60208-3113, USACorrespondence e-mail:
ibers@chem.northwestern.edu**Key indicators**Single-crystal X-ray study
 $T = 153$ K
Mean $\sigma(\text{Cu}-\text{S}) = 0.001$ Å
 R factor = 0.023
 wR factor = 0.054
Data-to-parameter ratio = 17.7For details of how these key indicators were
automatically derived from the article, see
<http://journals.iucr.org/e>.

Rubidium diholmium tricopper pentasulfide, RbHo₂Cu₃S₅, crystallizes in the orthorhombic space group *Cmcm* and is isostructural with RbSm₂Ag₃Se₅. In the asymmetric unit, the site symmetries of atoms Rb, Cu1, and S2 are *mm* and those of the other atoms are *m*. The structure has a three-dimensional tunnel framework, with tunnels built from HoS₆ octahedra and CuS₄ tetrahedra. The tunnels are filled with Rb atoms.

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Ternary and quaternary rare-earth chalcogenides containing a combination of *d*- and *f*-elements have been reviewed recently (Mitchell & Ibers, 2002). We report here the structure of RbHo₂Cu₃S₅, a new member of this large family. RbHo₂Cu₃S₅, which has the RbSm₂Ag₃Se₅ structure type (Huang & Ibers, 2000), crystallizes in space group *Cmcm* of the orthorhombic system. In the asymmetric unit (Fig. 1), the site symmetries of atoms Rb, Cu1, and S2 are *mm* and those of the other atoms are *m*. The structure of RbHo₂Cu₃S₅ (Fig. 2) possesses a three-dimensional tunnel framework built from HoS₆ octahedra and CuS₄ tetrahedra. The tunnel, comprising ten-membered rings of six Cu–S bonds and four Ho–S bonds, is only large enough in cross-section to accommodate one Rb atom. Each Rb atom is surrounded by a bicapped trigonal prism of eight S atoms, with Rb–S separations ranging from 3.293 (1) to 3.460 (1) Å, comparable with those of 3.247 (2)–3.7951 (4) Å in RbNd₂CuS₄ (Huang & Ibers, 2000). The Ho–S bond distances range from 2.6497 (8) to 2.787 (1) Å, consistent with those of 2.672 (2)–2.8009 (3) Å in K₂Ho₄Cu₄S₉ (Yao *et al.*, 2003), and the Cu–S bond distances range from 2.321 (1) to 2.547 (2) Å, comparable with those of 2.3448 (9) to 2.534 (2) Å in K₂Ho₄Cu₄S₉ (Yao *et al.*, 2003).

**Figure 1**

A view of the asymmetric unit of RbHo₂Cu₃S₅, with displacement ellipsoids drawn at the 90% probability level.

Experimental

RbHo₂Cu₃S₅ was obtained as yellow needles from a solid-state reaction of Rb₂S₃ (1.2 mmol), Ho (Aldrich, 99%, 1.0 mmol), Cu (Aldrich, 99.999%, 0.5 mmol), and S (Aldrich, 99.5%, 2.0 mmol). The Rb₂S₃ reactive flux (Sunshine *et al.*, 1987) was prepared by the stoichiometric reaction of Rb (Aldrich, 98+%) and S in liquid NH₃. The reactants were loaded into a fused-silica tube under an argon atmosphere in a glove-box. The tube was sealed under a 10⁻⁴ Torr atmosphere and then placed in a computer-controlled furnace. The sample was heated to 1173 K over a period of 25 h, kept at 1173 K for 3 d, slowly cooled at a rate of 10 K h⁻¹ to 473 K, and then cooled rapidly to room temperature.

Crystal data

RbHo₂Cu₃S₅
M_r = 766.25
 Orthorhombic, *Cmcm*
a = 3.9451 (11) Å
b = 13.915 (4) Å
c = 16.408 (5) Å
V = 900.8 (4) Å³
Z = 4
D_x = 5.650 Mg m⁻³

Mo *K*α radiation
 Cell parameters from 4507 reflections
 $\theta = 2.5\text{--}29.0^\circ$
 $\mu = 30.77\text{ mm}^{-1}$
T = 153 (2) K
 Needle, yellow
 0.42 × 0.068 × 0.030 mm

Data collection

Bruker SMART 1000 CCD diffractometer
 ω scans
 Absorption correction: numerical face indexed
T_{min} = 0.047, *T_{max}* = 0.405
 5433 measured reflections

673 independent reflections
 661 reflections with *I* > 2σ(*I*)
R_{int} = 0.050
 $\theta_{\text{max}} = 29.0^\circ$
h = -5 → 5
k = -18 → 18
l = -21 → 21

Refinement

Refinement on *F*²
R [*F*² > 2σ(*F*²)] = 0.023
wR (*F*²) = 0.054
S = 1.39
 673 reflections
 38 parameters

$w = 1/[\sigma^2(F_o^2) + (0.03P)^2]$
 where $P = (F_o^2 + 2F_c^2)/3$
 (Δ/σ)_{max} = 0.001
 $\Delta\rho_{\text{max}} = 2.37\text{ e \AA}^{-3}$
 $\Delta\rho_{\text{min}} = -2.55\text{ e \AA}^{-3}$
 Extinction correction: *SHELXL97*
 Extinction coefficient: 0.00404 (19)

Table 1

Selected geometric parameters (Å, °).

Rb—S3	3.2929 (15)	Ho—S3 ^{vi}	2.7865 (10)
Rb—S2 ⁱ	3.3410 (15)	Cu1—S2 ^{vii}	2.3212 (10)
Rb—S1 ⁱⁱ	3.4604 (12)	Cu1—S1 ^{iv}	2.5438 (14)
Ho—S2 ⁱⁱⁱ	2.6497 (8)	Cu2—S1 ^{viii}	2.3641 (14)
Ho—S3 ^{iv}	2.6957 (14)	Cu2—S3 ^v	2.3674 (8)
Ho—S1 ^v	2.6995 (9)	Cu2—S1 ^{iv}	2.5473 (15)
S2 ⁱⁱⁱ —Ho—S3 ^{iv}	172.13 (4)	S3 ^{vi} —Ho—S3 ^v	90.13 (4)
S2 ⁱⁱⁱ —Ho—S1 ^v	92.47 (3)	S2 ^{vii} —Cu1—S2 ⁱ	116.38 (7)
S3 ^{iv} —Ho—S1 ^v	92.89 (3)	S2 ⁱ —Cu1—S1 ^{iv}	105.05 (2)
S1 ^v —Ho—S1 ^{vi}	93.89 (4)	S1 ^{iv} —Cu1—S1	120.96 (6)
S2 ⁱⁱⁱ —Ho—S3 ^{vi}	87.95 (4)	S1 ^{viii} —Cu2—S3 ^v	108.94 (4)
S3 ^{iv} —Ho—S3 ^{vi}	86.50 (3)	S3 ^v —Cu2—S3 ^{vi}	112.86 (5)
S1 ^v —Ho—S3 ^{vi}	178.05 (3)	S1 ^{viii} —Cu2—S1 ^{iv}	115.43 (4)
S1 ^{vi} —Ho—S3 ^{vi}	87.99 (3)	S3 ^v —Cu2—S1 ^{iv}	105.36 (4)

Symmetry codes: (i) $x - \frac{1}{2}, y - \frac{1}{2}, z$; (ii) $\frac{1}{2} + x, \frac{1}{2} + y, \frac{1}{2} - z$; (iii) $-x, 1 - y, 1 - z$; (iv) $x, y, \frac{1}{2} - z$; (v) $\frac{1}{2} - x, \frac{1}{2} - y, \frac{1}{2} + z$; (vi) $-\frac{1}{2} - x, \frac{1}{2} - y, \frac{1}{2} + z$; (vii) $\frac{1}{2} + x, y - \frac{1}{2}, z$; (viii) $-x, -y, \frac{1}{2} + z$.

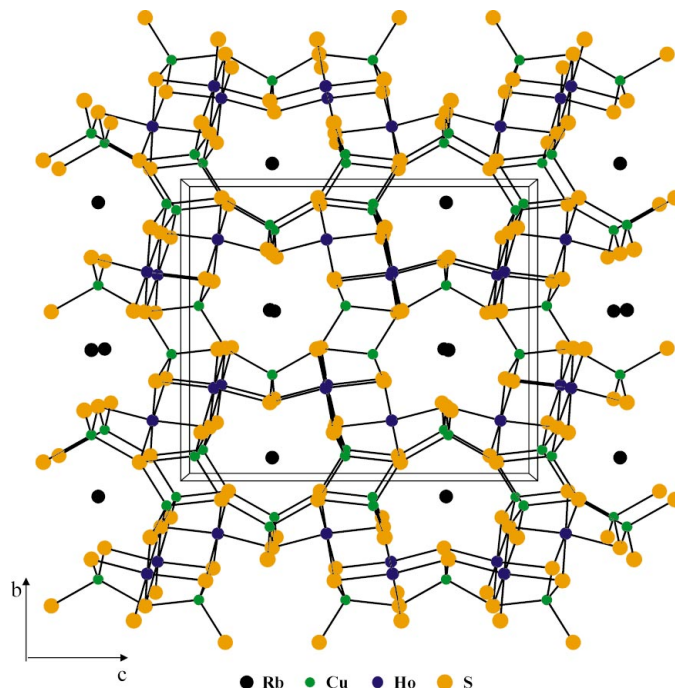


Figure 2
 The structure of RbHo₂Cu₃S₅, viewed down [100].

The highest residual electron density is 0.87 Å⁻³ from the Ho site and the deepest hole is 0.70 Å⁻³ from this same site.

Data collection: *SMART* (Bruker, 2003); cell refinement: *SAINT* (Bruker, 2003); data reduction: *SAINT*; program(s) used to solve structure: *SHELXTL* (Sheldrick, 2003); program(s) used to refine structure: *SHELXTL*; molecular graphics: *XP* in *SHELXTL*; software used to prepare material for publication: *SHELXTL*.

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